





TPS3762-Q1 SNVSCE6A – OCTOBER 2023 – REVISED MAY 2024

TPS3762-Q1 Automotive 65V Window (OV & UV) Supervisor with Built-In Self-Test and Latch

## 1 Features

Texas

INSTRUMENTS

- ASIL-D Functional Safety-Compliant
  - Documentation to aid ISO 26262 system design
  - Systematic capability up to ASIL-D
  - Hardware capability up to ASIL-D
- AEC-Q100 qualified for automotive applications
   Device temperature grade 1: -40°C to +125°C
- Device flexibility to meet design requirements
  - Wide voltage threshold range: 2.7V to 60V
  - 800mV option use with external resistor divider to set threshold
  - Built-in hysteresis (2%, 5%, and 10% options)
  - Fixed and programmable reset time delay
  - Fixed and programmable detection delay
- Monitor high voltage power rails
  - Wide input voltage range: 2.7V to 65V
  - Reverse polarity protection on sense pin -65V
- Fast UV/OV protection in 12/24/48V systems
  - Output reset latching feature
  - Ultra-fast detection time delay option(5µs)
  - Built-In Self-Test

## **2** Applications

- Sensor fusion and cameras
- Digital cockpit processing unit
- On-board charger
- ADAS domain controller

## **3 Description**

The TPS3762-Q1 is a 65V input voltage supervisor with 4 $\mu$ A I<sub>DD</sub>, 0.9% accuracy, fast detection time (5 $\mu$ s), and a Built-In Self-Test feature. This device can be connected directly to 12V / 24V automotive battery systems for continuous monitoring of overvoltage (OV) and undervoltage (UV) conditions; with the internal resistor divider, the TPS3762-Q1 offers the smallest total solution size. Wide hysteresis voltage options are available to ignore large voltage transients and prevent false reset signals.

The separate VDD and SENSE pins allow redundancy sought by high-reliability systems and SENSE can monitor higher and lower voltages than VDD. Optional use of external resistors are supported by the high impedance input of the SENSE pin. CTS and CTR pins allow delay adjustability on the falling and rising edges of the RESET signal. The CTS functions as a debouncer by ignoring voltage glitches on the monitored voltage rails.

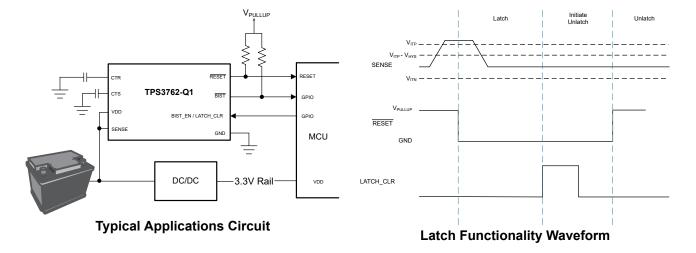
The TPS3762-Q1 is available in a 2.9mm × 1.6mm SOT23 8-pin package.

**Device Information** 

PART NUMBER	PACKAGE (1)	BODY SIZE (NOM) (2)
TPS3762-Q1	SOT-23 (8) (DDF)	2.9mm x 1.6mm

(1) For package details, see the mechanical drawing addendum at the end of the data sheet.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.





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## 4 Device Nomenclature

Device Decoder in Section 5 describe how to decode certain device function of the device based on its part number. Not all part numbers follow this nomenclature. Use Table 4-1 as the part number decoding table for all devices.

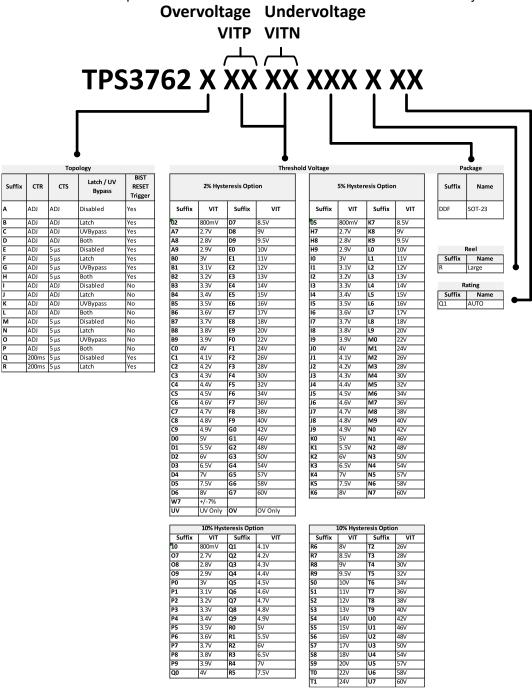
ORDERABLE PART NAME	Overvoltage (V <sub>ITP</sub> )	Overvoltage Hysteresis	Undervoltage (V <sub>ITN</sub> )	Undervoltage Hysteresis	CTR / CTS	Latch / UVbypass	BIST RESET Trigger
TPS3762D02OVDDFRQ1	800mV	2%	N/A	N/A	ADJ / ADJ	Both	Yes

### Table 4-1. Device Configuration Table



## 5 Device Comparison

Device Decoder shows some of the device naming nomenclature of the TPS3762-Q1. Not all device namings follow this nomenclature table. For a detailed breakdown of every device part number by threshold voltage options, BIST configurations, Latch configurations, CTR options, CTS options, and UV bypass, see Section 4 for more details. Contact TI sales representatives or on TI's E2E forum for detail and availability of other options.



- 1. Suffix 02, 05, and 10 with VIT of 800mV corresponds to the adjustable variant, do not have internal voltage divider
- 2. Not all TPS3762-Q1 devices can be decoded by this table. Refer to Section 4 for a decoding table by part number.



# **6** Pin Configuration and Functions

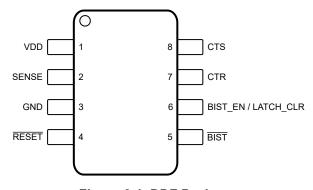


Figure 6-1. DDF Package, 8-Pin SOT-23, TPS3762-Q1 (Top View)

**Table 6-1. Pin Functions** 

PIN		I/O	DESCRIPTION	
NAME	NO.		DESCRIPTION	
VDD	1	I	Input Supply Voltage: Supply voltage pin. For noisy systems, bypass with a $0.1\mu$ F capacitor to GND.	
SENSE	2	I	Sense Voltage: Connect this pin to the supply rail that must be monitored. See Section 8.3.2 for more details. Sensing Topology: Overvoltage (OV) or Undervoltage (UV) or Window (OV + UV)	
GND	3	-	Ground. Ground pin. All GND pins must be electrically connected to the board ground.	
RESET	4	0	Output Reset Signal: RESET asserts when SENSE crosses the voltage threshold after the sense time delay, set by CTS, and remains asserted for the reset time delay period, set by CTR, after SENSE transitions out of a fault condition. For latch variants RESET remains asserted until the latch is cleared. The active low open-drain reset output requires an external pullup resistor. See Section 8.3.3.2 for more details. Output topology: Open-Drain Active-Low	
BIST	5	0	$\begin{array}{l} \textbf{Built-In Self-Test: } \overline{\texttt{BIST}} \text{ asserts when a logic high input occurs on the } \texttt{BIST}\_\texttt{EN} / \\ \texttt{LATCH\_CLR or } \texttt{BIST\_EN} \text{ pin, this initiates the internal } \texttt{BIST} \text{ testing. } \overline{\texttt{BIST}} \text{ recovers after} \\ \texttt{t}_{\overline{\texttt{BIST}}} \text{ to signify } \texttt{BIST} \text{ completed successfully. } \overline{\texttt{BIST}} \text{ remains asserted for a time period longer} \\ \texttt{t}_{\overline{\texttt{BIST}}} \text{ if there is a failure during } \texttt{BIST}. \\ \overline{\texttt{BIST}} \text{ active-low open-drain output requires an} \\ \texttt{external pullup resistor. } \text{See Section } \$.3.6 \text{ for more details.} \end{array}$	
BIST_EN / LATCH_CLR	6	I	<b>Built-in Self-test Enable and Latch Clear:</b> A logic high input must occur on the BIST_EN / LATCH_CLR to initate BIST and clear a latched OV/UV fault. See Section 8.3.6 for more details.	
CTR	7	0	<b>RESET Time Delay:</b> User-programmable reset time delay for RESET. Connect an extern capacitor for adjustable time delay or leave the pin floating for the shortest delay. See Section8.3.4 for more details.	
CTS	8	0	<b>SENSE Time Delay:</b> User-programmable sense time delay for SENSE. Connect an external capacitor for adjustable time delay or leave the pin floating for the shortest delay. See Section 8.3.5 for more details.	



## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range, unless otherwise noted (1)

		MIN	MAX	UNIT
Voltage	V <sub>DD</sub> , V <sub>SENSE(Adjustable)</sub> , V <sub>RESET</sub>	-0.3	70	V
Voltage	V <sub>SENSE(Fixed)</sub>	-65	70	V
Voltage	V <sub>CTS</sub> , V <sub>CTR</sub>	-0.3	6	V
Voltage	V <sub>BIST</sub> , V <sub>BIST_EN</sub> , V <sub>BIST_EN/LATCH_CLR</sub>	-0.3	6	V
Current	I <sub>RESET</sub> , I <sub>BIST</sub>		10	mA
Temperature <sup>(2)</sup>	Operating junction temperature, T <sub>J</sub>	-40	150	°C
Temperature <sup>(2)</sup>	Operating Ambient temperature, T <sub>A</sub>	-40	150	°C
Temperature <sup>(2)</sup>	Storage, T <sub>stg</sub>	-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) As a result of the low dissipated power in this device, it is assumed that  $T_J = T_A$ .

## 7.2 ESD Ratings

			VALUE	UNIT
V	Electrostatic discharge	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	±2000	V
V(ESD)		Charged device model (CDM), per AEC Q100-011	±750	v

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

## 7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM MAX	UNIT
Voltage	V <sub>DD</sub>	2.7	65	V
Voltage	V <sub>SENSE</sub> , V <sub>RESET</sub>	0	65	V
Voltage	V <sub>CTS</sub> , V <sub>CTR</sub>	0	5.5	V
Voltage	VBIST, VBIST_EN, VBIST_EN/LATCH_CLR	0	5.5	V
Current	IRESET, IBIST	0	5	mA
T <sub>J</sub> <sup>(1)</sup>	Junction temperature (free air temperature)	-40	125	°C

(1) As a result of the low dissipated power in this device, it is assumed that  $T_J = T_A$ .



## 7.4 Thermal Information

		TPS3762-Q1	
	THERMAL METRIC <sup>(1)</sup>	DDF	UNIT
		8-PIN	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	154.6	°C/W
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	77.4	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	73.2	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	4.8	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	72.9	°C/W
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.



## 7.5 Electrical Characteristics

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD (MAX)}$ , CTR = CTS = open, output  $\overline{RESET}$  pull-up resistor  $R_{PU}$  = 10k $\Omega$ , voltage  $V_{PU}$  = 5.5V, output BIST pull-up resistor  $R_{PU}$  = 10k $\Omega$ , voltage  $V_{PU}$  = 5.5V, and load  $C_{LOAD}$  = 10pF. The operating free-air temperature range  $T_A$  = - 40°C to 125°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{DD}$  = 12V and  $V_{IT}$  = 6.5V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUP	PLY				I	
V <sub>DD</sub>	Supply Voltage		2.7		65	V
UVLO <sup>(1)</sup>	Undervoltage Lockout	V <sub>DD</sub> rising above V <sub>DD (MIN)</sub>			2.6	V
UVLO(HYS) (1)	Undervoltage Lockout Hysteresis	$V_{DD}$ falling below $V_{DD (MIN)}$		500		mV
V <sub>POR(RESET)</sub>	Power on Reset Voltage <sup>(2)</sup> RESET, Active Low (Open-Drain)	V <sub>OL(MAX)</sub> = 300mV I <sub>OUT (Sink)</sub> = 15µA			1.4	V
V <sub>POR(BIST)</sub>	Power on Reset Voltage <sup>(2)</sup> BIST, Active Low (Open-Drain)	V <sub>OL(MAX)</sub> = 300mV I <sub>OUT (Sink)</sub> = 15µA			1.4	V
I <sub>DD</sub>	Supply current into $V_{DD}$ pin	$V_{IT} = 800 \text{mV}$ $V_{DD (MIN)} \le V_{DD} \le V_{DD} (MAX)$		4	8.1	μA
SENSE (Inpu	t)					
ISENSE	Input current	V <sub>IT</sub> = 800mV			200	nA
V <sub>ITN</sub>	Input Threshold Negative (Undervoltage)	V <sub>IT</sub> = 800mV <sup>(3)</sup>	-0.9		0.9	%
V <sub>ITP</sub>	Input Threshold Positive (Overvoltage)	V <sub>IT</sub> = 800mV <sup>(3)</sup>	-0.9		0.9	%
V <sub>HYS</sub>	Hysteresis Accuracy <sup>(4)</sup>	V <sub>IT</sub> = 0.8V V <sub>HYS</sub> Range = 2%	1.5	2	2.5	%
RESET (Outp	out)	-	·			
I <sub>lkg(OD)</sub>	Open-Drain leakage	V <sub>RESET</sub> = 5.5V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
I <sub>lkg(OD)</sub>	Open-Drain leakage	V <sub>RESET</sub> = 65V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
V <sub>OL</sub> <sup>(5)</sup>	Low level output voltage	$2.7V \le VDD \le 65V$ $I_{RESET} = 2.7mA$			350	mV



## 7.5 Electrical Characteristics (continued)

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD} (MAX)$ , CTR = CTS = open, output  $\overline{\text{RESET}}$  pull-up resistor  $R_{PU} = 10k\Omega$ , voltage  $V_{PU} = 5.5V$ , output  $\overline{\text{BIST}}$  pull-up resistor  $R_{PU} = 10k\Omega$ , voltage  $V_{PU} = 5.5V$ , and load  $C_{LOAD} = 10$  pF. The operating free-air temperature range  $T_A = -40^{\circ}$ C to  $125^{\circ}$ C, unless otherwise noted. Typical values are at  $T_A = 25^{\circ}$ C and  $V_{DD} = 12V$  and  $V_{IT} = 6.5V$  ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	ТҮР	MAX	UNIT
Capacitor T	iming (CTS, CTR)	· · ·				
R <sub>CTR</sub>	Internal resistance (CTR)		2.96	3.7	4.44	MΩ
R <sub>CTS</sub>	Internal resistance (CTS)		2.96	3.7	4.44	MΩ
Built-in Self	-test	· · · · ·	·			
I <sub>lkg(BIST)</sub>	Open-Drain leakage	V <sub>BIST</sub> = 5.5V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
I <sub>lkg(BIST)</sub>	Open-Drain leakage	V <sub>BIST</sub> = 3.3V V <sub>ITN</sub> < V <sub>SENSE</sub> < V <sub>ITP</sub>			300	nA
V <sub>BIST_OL</sub>	Low level output voltage	$2.7V \le VDD \le 65V$ $I_{\overline{BIST}} = 5mA$			300	mV
V <sub>BIST_EN</sub>	BIST_EN pin logic low input				500	mV
V <sub>BIST_EN</sub>	BIST_EN pin logic high input		1300			mV
V <sub>BIST_EN</sub> / LATCH_CLR	LATCH_CLR pin logic low input				500	mV
V <sub>BIST_EN/</sub> LATCH_CLR	LATCH_CLR pin logic high input		1300			mV

(1) When  $V_{DD}$  voltage falls below UVLO, RESET is asserted.  $V_{DD}$  slew rate  $\leq 100$ mV /  $\mu$ s

(2) V<sub>POR</sub> is the minimum V<sub>DD</sub> voltage for a controlled output state. Below V<sub>POR</sub>, the output cannot be determined. V<sub>DD</sub> slew rate ≤ 100mV/µs

(3) For adjustable voltage guidelines and resistor selection refer to Adjustable Voltage Thresholds in Application and Implementation section

(4) Hysteresis is with respect to V<sub>ITP</sub> and V<sub>ITN</sub> voltage threshold. V<sub>ITP</sub> has negative hysteresis and V<sub>ITN</sub> has positive hysteresis.

(5) For V<sub>OH</sub> and V<sub>OL</sub> relation to output variants refer to Timing Figures after the Timing Requirement Table

### 7.6 Switching Requirements

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD}$  (MAX), CTR = CTS = open and enabled, output RESET pull-up resistor R<sub>PU</sub> = 10k $\Omega$ , voltage V<sub>PU</sub> = 5.5V, output BIST pull-up resistor R<sub>PU</sub> BIST = 10k $\Omega$ , voltage V<sub>PU</sub> BIST = 5.5V, and load C<sub>LOAD</sub> = 10pF. The operating free-air temperature range T<sub>A</sub> = -40°C to 125°C, unless otherwise noted. Typical values are at T<sub>A</sub> = 25°C and V<sub>DD</sub> = 12V and V<sub>IT</sub> = 6.5V (V<sub>IT</sub> refers to V<sub>ITN</sub> or V<sub>ITP</sub>).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Common Sv	vitching Requirements		1		I	
t <sub>CTR(No Cap)</sub>	RESET release time delay (CTR) <sup>(1)</sup>	VIT = 800mV C <sub>CTR</sub> = Open 20% Overdrive from Hysteresis		350	600	μs
t <sub>CTS(No Cap)</sub>	Sense detect time delay (CTS) <sup>(2)</sup>	VIT = 800mV C <sub>CTS</sub> = Open 20% Overdrive from V <sub>IT</sub>		85	100	μs
t <sub>SD</sub>	Startup Delay <sup>(3)</sup>	C <sub>CTR</sub> = Open		1		ms
BIST Switch	ing Requirements		1			
t <sub>BIST_en_pd</sub>	Rising edge of BIST_EN to BIST asserting			2.3		μs
t <sub>BIST_en_pd</sub>	Rising edge of BIST_EN to RESET asserting			2.3		μs
t <sub>BIST_recover</sub>	Rising edge of BIST to SENSE input valid	C <sub>CTR</sub> = Open, BIST = Enabled		350	600	μs
t <sub>BIST</sub>	BIST run time				3.5	ms
t <sub>SD+BIST</sub>	Startup time with BIST run time				4.5	ms
LATCH Swit	ching Requirements				ľ	
t <sub>BIST_EN/</sub> LATCH_CLR_R ecover	Rising edge of BIST to SENSE input valid	C <sub>CTR</sub> = Open, BIST = Disabled		10		μs

#### (1) CTR Reset detect time delay:

Overvoltage active-low output is measure from V\_{ITP - HYS} to V\_{OH} Undervoltage active-low output is measure from V\_{ITN + HYS} to V\_{OH}

(2) CTS Sense detect time delay: Overvoltage active-low output is measure from V<sub>ITP</sub> to V<sub>OL</sub> Undervoltage active-low output is measure from V<sub>ITN</sub> to V<sub>OL</sub>

(3) During the power-on sequence, V<sub>DD</sub> must be at or above V<sub>DD (MIN)</sub> for at least t<sub>SD+BIST</sub> + t<sub>CTR</sub> before the output is in the correct state based on V<sub>SENSE</sub>.

 $t_{SD}$  time includes the propagation delay (C<sub>CTR</sub> = Open). Capacitor on CTR will add time to  $t_{SD}$ .



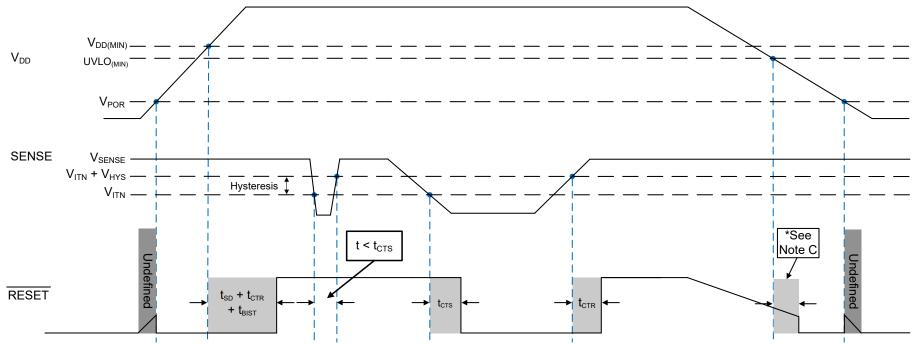
### 7.7 Timing Requirements

At  $V_{DD(MIN)} \le V_{DD} \le V_{DD (MAX)}$ , CTR = CTS = open and enabled, output  $\overline{RESET}$  pull-up resistor  $R_{PU}$  = 10k $\Omega$ , voltage  $V_{PU}$  = 5.5V, output  $\overline{BIST}$  pull-up resistor  $R_{PU}$ \_ $\overline{BIST}$  = 10k $\Omega$ , voltage  $V_{PU}$ \_ $\overline{BIST}$  = 5.5V, and load  $C_{LOAD}$  = 10pF. The operating free-air temperature range  $T_A$  = -40°C to 125°C, unless otherwise noted. Typical values are at  $T_A$  = 25°C and  $V_{DD}$  = 12V and  $V_{IT}$  = 6.5V ( $V_{IT}$  refers to  $V_{ITN}$  or  $V_{ITP}$ ).

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Common tin	ning parameters				· · ·	
BIST timing	parameters					
t <sub>BIST_en Glitch</sub>	BIST_EN Glitch immunity			1.1		μs
t <sub>BIST_en</sub>	Minimum BIST_EN input width to initate BIST			1.2	8	μs
LATCH timir	ng parameters					
t <sub>BIST_EN/</sub> LATCH_CLR Glitch	Latch Glitch immunity			1.5		μs
t <sub>BIST_EN/</sub> LATCH_CLR	Latch input width to clear latch			1.6		μs



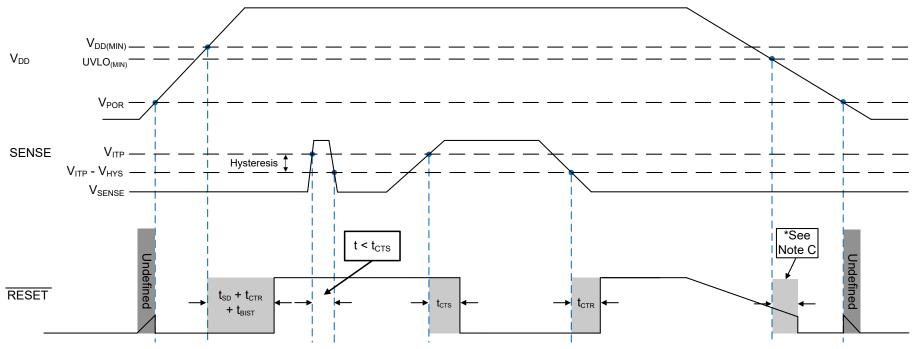
## 8 Timing Diagrams



- A. The timing diagram assumes the open-drain output RESET pin is connected via an external pull-up resistor to V<sub>DD</sub>.
- B. Be advised that Figure 8-1 shows the V<sub>DD</sub> falling slew rate is slow or the V<sub>DD</sub> decay time is much larger than the propagation detect delay (t<sub>CTR</sub>) time.
- C.  $\overline{\text{RESET}}$  is asserted when V<sub>DD</sub> goes below the UVLO<sub>(MIN)</sub> threshold after the time delay, t<sub>CTR</sub>, is reached.

#### Figure 8-1. SENSE Undervoltage (UV) Timing Diagram





- A. The timing diagram assumes the open-drain output RESET pin is connected via an external pull-up resistor to V<sub>DD</sub>.
- B. Be advised that Figure 8-2 shows the  $V_{DD}$  falling slew rate is slow or the  $V_{DD}$  decay time is much larger than the propagation detect delay ( $t_{CTR}$ ) time.
- C. RESET is asserted when  $V_{DD}$  goes below the UVLO<sub>(MIN)</sub> threshold after the time delay, t<sub>CTR</sub>, is reached.

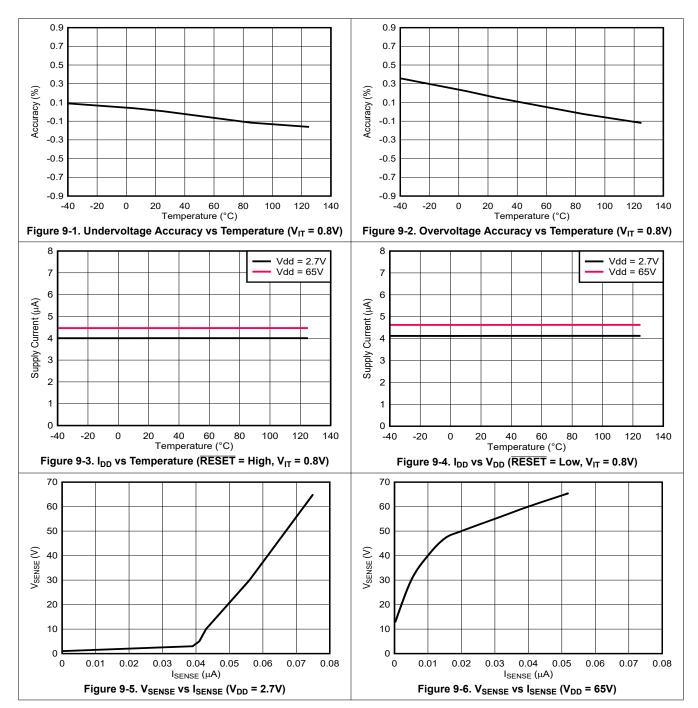
#### Figure 8-2. SENSE Overvoltage (OV) Timing Diagram





## **9** Typical Characteristics

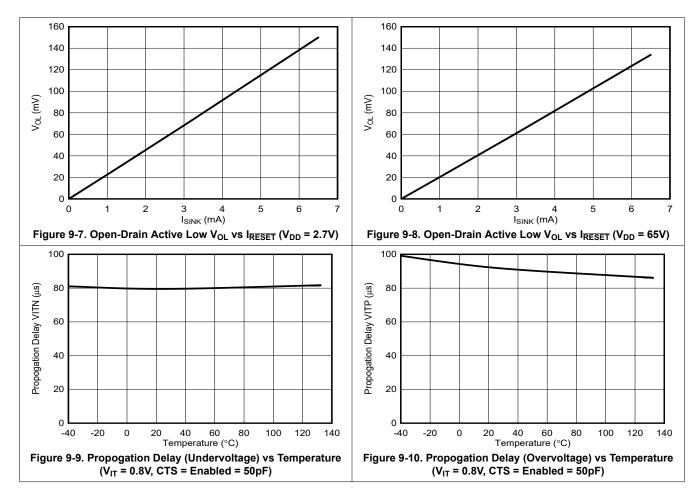
Typical characteristics show the typical performance of the TPS3762-Q1 device. Test conditions are taken at  $T_A = 25^{\circ}C$ , unless otherwise noted.





## **9** Typical Characteristics (continued)

Typical characteristics show the typical performance of the TPS3762-Q1 device. Test conditions are taken at  $T_A = 25^{\circ}C$ , unless otherwise noted.





## 10 Detailed Description

## 10.1 Overview

The TPS3762-Q1 is a family of high voltage and low quiescent current voltage supervisors with overvoltage and undervoltage threshold voltage options, delay timings, Built-In Self-Test, and latch. The TPS3762-Q1 over and undervoltage thresholds are device specific and are offered in either adjustable thresholds or fixed threholds. The adjustable threshold option uses an external resistor ladder to make a voltage divider on SENSE pin which uses the internal 800mV threshold to trigger overvoltage and undervoltage faults. The benefit of using an adjustable option with external resistors is the faster reaction speed compared to a fixed internal threshold variant. The TPS3762-Q1 fixed threshold option utilizes an integrated voltage divider to eliminate the need for external resistors and provides a lower system leakage current.

VDD, SENSE and RESET pins can support 65V continuous operation. SENSE has -65V reverse polarity protection. VDD, SENSE, and RESET voltage levels can be independent of each other. TPS3762-Q1 includes a reset output latching feature that holds the output active to help system achieve safe state. Fixed and programmable sense and reset delay are available to avoid false resets and false reset releases.

#### **10.2 Functional Block Diagram**

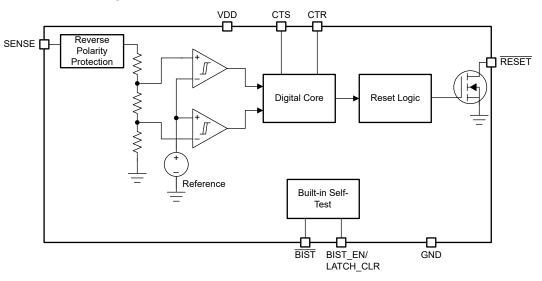
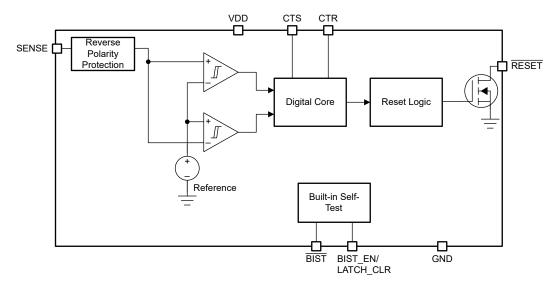


Figure 10-1. Fixed Threshold Functional Block Diagram







### **10.3 Feature Description**

### 10.3.1 Input Voltage (VDD)

VDD operating voltage ranges from 2.7V to 65V. An input supply capacitor is not required for this device; however, if the input supply is noisy good analog practice is to place a  $0.1\mu$ F capacitor between the VDD and GND.

VDD needs to be at or above  $V_{DD(MIN)}$  for at least the start-up time delay (t<sub>SD</sub>) for the device to be fully functional.

VDD voltage is independent of  $V_{\text{SENSE}}$  and  $V_{\text{RESET}}$ , meaning that VDD can be higher or lower than the other pins.

#### 10.3.1.1 Undervoltage Lockout (V<sub>POR</sub> < V<sub>DD</sub> < UVLO)

When the voltage on  $V_{DD}$  is less than the UVLO voltage, but greater than the power-on reset voltage ( $V_{POR}$ ), the RESET and BIST pins will be asserted, regardless of the voltage at SENSE pin.

#### 10.3.1.2 Power-On Reset ( $V_{DD} < V_{POR}$ )

When the voltage on VDD is lower than the power on reset voltage ( $V_{POR}$ ), the output signal is undefined and is not to be relied upon for proper device function.

Note: Figure 10-3 and Figure 10-4 assume an external pull-up resistor is connecting the RESET pin to VDD.

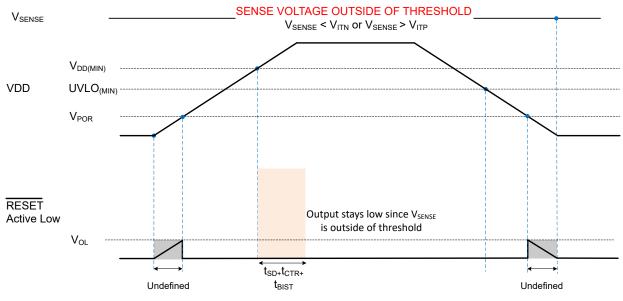


Figure 10-3. Power Cycle (SENSE Outside of Nominal Voltage)



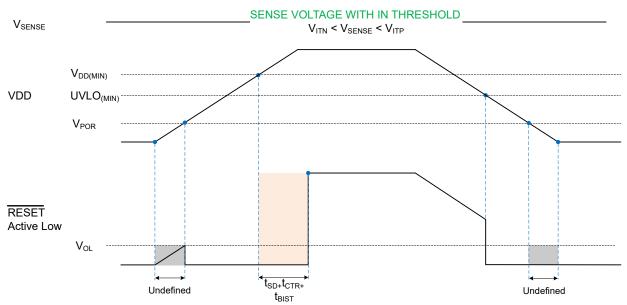


Figure 10-4. Power Cycle (SENSE Within Nominal Voltage)



#### 10.3.2 SENSE

The SENSE pin connects to the supply rail that is to be monitored. The sense pin on each device is configured to monitor either overvoltage (OV), undervoltage (UV), or window (OV&UV) conditions. TPS3762-Q1 device offers built-in hysteresis that provides noise immunity and maintains stable operation.

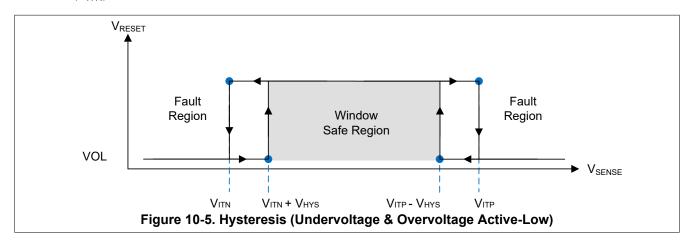
Although not required in most cases, for noisy applications where  $t_{CTS}$  is not sufficient glitch rejection, good analog design practice is to place a 10nF to 100nF bypass capacitor at the SENSE input to reduce sensitivity to transient voltages on the monitored signal. SENSE can be connected directly to VDD pin.

#### 10.3.2.1 Reverse Polarity Protection

The TPS3762-Q1 has reverse polarity protection on the sense pin up to -65V. This allows the TPS3762-Q1 to support accidental or test simulated reverse connections without damaging the device. This protection permits the TPS3762-Q1 to connect directly off of the supply prior to any reverse polarity protection diodes for accurate voltage measurement.

#### 10.3.2.2 SENSE Hysteresis

TPS3762-Q1 device offers built-in hysteresis around the UV and OV thresholds to avoid erroneous RESET deassertions. The hysteresis is opposite to the threshold voltage; for overvoltage options the hysteresis is subtracted from the positive threshold ( $V_{ITP}$ ), for undervoltage options hysteresis is added to the negative threshold ( $V_{ITP}$ ).



	TARGET		
ADJUSTABLE THRESHOLD	TOPOLOGY	RELEASE VOLTAGE (V)	DEVICE HYSTERESIS OPTION
800mV	Overvoltage	784mV	-2%
800mV	Overvoltage	760mV	-5%
800mV	Overvoltage	720mV	-10%
800mV	Undervoltage	816mV	2%
800mV	Undervoltage	840mV	5%
800mV	Undervoltage	880mV	10%

#### Table 10-1. Common Adjustable Hysteresis Lookup Table

Table 10-1 shows a sample of hysteresis for the 800mV adjustable variant of TPS3762-Q1.

Knowing the amount of hysteresis voltage, the release voltage for the undervoltage (UV) channel is ( $V_{ITN} + V_{HYS}$ ) and for the overvoltage (OV) channel is ( $V_{ITP} - V_{HYS}$ ).

Undervoltage (UV)

V<sub>ITN</sub> = 800mV

Voltage Hysteresis (V<sub>HYS</sub>) = 2% = 16mV

Hysteresis Accuracy = +1.5% to +2.5% = 16.24mV to 16.4mV

Release Voltage = V<sub>ITN</sub> + V<sub>HYS</sub> = 816.24mV to 816.4mV

Overvoltage (OV)

 $V_{ITP} = 800 mV$ 

Voltage Hysteresis (V<sub>HYS</sub>) = 2% = 16mV

Hysteresis Accuracy = +1.5% to +2.5% = 16.24mV to 16.4mV

Release Voltage =  $V_{ITP}$  -  $V_{HYS}$  = 783.6mV to 783.76mV



#### 10.3.3 Output Logic Configurations

TPS3762-Q1 is a single channel device that has a single input SENSE pin and a single RESET pin. The single RESET is available only with open drain topology.

#### 10.3.3.1 Open-Drain

Open-drain output requires an external pull-up resistor to hold the voltage high to the required voltage logic. Connect the pull-up resistor to the proper voltage rail to enable the output to be connected to other devices at the correct interface voltage levels.

To select the right pull-up resistor consider system  $V_{OH}$  and the Open-Drain Leakage Current ( $I_{lkg}$ ) provided in the electrical characteristics, high resistors values will have a higher voltage drop affecting the output voltage high. The open-drain output can be connected as a wired-AND logic with other open-drain signals such as another TPS3762-Q1 open-drain output pin.

#### 10.3.3.2 Active-Low (RESET)

RESET (active low) denoted with a bar above the pin label. RESET remains high voltage (V<sub>OH</sub>, deasserted) as long as sense voltage is in normal operation within the threshold boundaries and VDD voltage is above UVLO. To assert a reset sense pins needs to meet the condition below:

- For undervoltage the SENSE voltage need to cross the lower boundary (V<sub>ITN</sub>).
- For overvoltage the SENSE voltage needs to cross the upper boundary (V<sub>ITP</sub>).



#### 10.3.3.3 Latching

The TPS3762-Q1 comes with the optional output reset latching feature, check the Section 5 to verify variant specific latch functionality. When using a variant with latch enabled ( $V_{BIST\_EN/LATCH\_CLR} < 0.5V$ ), whenever a fault, OV or UV, occurs RESET asserts and goes low and remains low until cleared by a logic high input ( $V_{BIST\_EN/LATCH\_CLR} > 1.3V$ ) on the BIST\_EN / LATCH\_CLR pin. If the SENSE pin is in a safe region and latch is disabled, the RESET deasserts after a delay. This delay is dependent on BIST and CTR timing. See Section 10.3.6 for more details. While  $V_{BIST\_EN/LATCH\_CLR} > 1.3V$ , the device is in latch disabled mode and the RESET does not latch for OV and UV on SENSE pin. While the device is in latch disabled mode the RESET asserts for OV and UV faults. When  $V_{BIST\_EN/LATCH\_CLR} < 0.5V$ , latch mode is enabled.

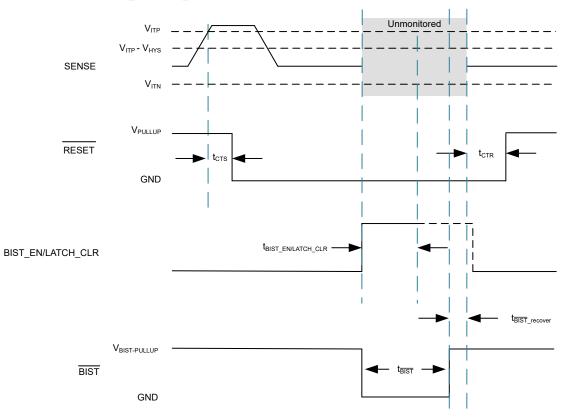


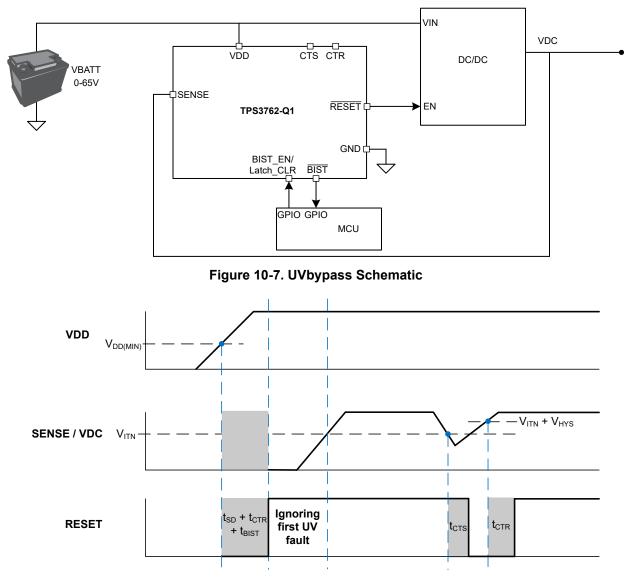
Figure 10-6. RESET Latch & Unlatch

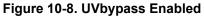


#### 10.3.3.4 UVBypass

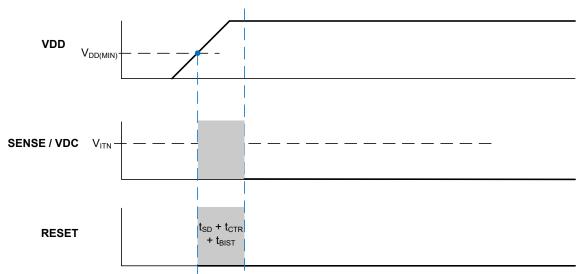
The TPS3762-Q1 comes with the optional undervoltage bypass (UVbypass) feature, check Section 5 to verify variant specific UVbypass functionality. When using a variant with UVbypass enabled, the first undervoltage event after  $V_{DD} > V_{POR}$  is ignored. In cases where an undervoltage event has not occurred UVbypass can be cleared by running BIST.

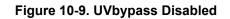
UVbypass is targeted at specific applications in which the TPS3762-Q1 is powered Off-battery and is monitoring the Off-battery DC-DC output, as shown in Figure 10-7. If the Off-battery DCDC output is outside of threshold the TPS3762-Q1 resets this device. See Figure 10-8 and Figure 10-9 for more details.













#### 10.3.4 User-Programmable Reset Time Delay

TPS3762-Q1 has adjustable reset release time delay with external capacitors.

- A capacitor on CTR programs the reset time delay of the output.
- No capacitor on this pin gives the fastest reset delay time indicated by t<sub>CTR</sub> in Section 7.6.
- Variants such as TPS3762Q use a fixed internal time delay. check the Section 5 to verify variant specific timing.

#### 10.3.4.1 Reset Time Delay Configuration

RESET time delay ( $t_{CTR}$ ) occurs when the RESET is transitioning from a fault state ( $V_{OL}$ ) to a non-fault state ( $V_{OH}$ ). The time delay ( $t_{CTR}$ ) can be programmed by connecting a capacitor between CTR pin and GND. For situations with a fault on SENSE after RESET recovers, the TPS3762-Q1 makes sure that the CTR capacitor is fully discharged before starting the recovery sequence. This makes sure that the programmed CTR time is maintained for consecutive faults.

The relationship between external capacitor  $C_{CTR EXT (typ)}$  and the time delay  $t_{CTR (typ)}$  is given by Equation 1.

 $t_{\text{CTR (typ)}} = R_{\text{CTR (typ)}} \times C_{\text{CTR}_{\text{EXT (typ)}}} + t_{\text{CTR (no cap)}} \times 10^{-6}$ 

(1)

 $R_{CTR (typ)}$  = is in mega ohms (M $\Omega$ )

 $C_{CTR EXT (typ)}$  = is given in microfarads (µF)

 $t_{CTR (typ)}$  = is the reset time delay/delays

The reset delay varies according to three variables: the external capacitor ( $C_{CTR\_EXT}$ ), CTR pin internal resistance ( $R_{CTR}$ ) provided in Section 7.5, and the constant ( $t_{CTR (no cap)}$ ) provided in Section 7.6. The minimum and maximum variance due to the constant is show in Equation 2 and Equation 3:

t <sub>CTR (min)</sub> = R <sub>CTR (min)</sub> x C <sub>CTR_EXT (min)</sub> + t <sub>CTR (no cap (min))</sub> x 10 <sup>-6</sup>	(2)

 $t_{\text{CTR}(\text{max})} = R_{\text{CTR}(\text{max})} \times C_{\text{CTR}_{\text{EXT}}(\text{max})} + t_{\text{CTR}(\text{no cap}(\text{max}))} \times 10^{-6}$ (3)

There is no limit to the capacitor on CTR pin. Having a too large of a capacitor value can cause very slow charge up (rise times) due to capacitor leakage and system noise can cause the internal circuit to hold RESET active.

\* Leakages on the capacitor can effect accuracy of reset time delay.



#### 10.3.5 User-Programmable Sense Delay

TPS3762-Q1 has adjustable sense release time delay with external capacitors.

- A capacitor on CTS programs the sense time delay of the input.
- No capacitor on this pin gives the fastest sense delay time indicated by t<sub>CTS</sub> in Section 7.7.
- The TPS3762-Q1 comes with an optional fixed internal time delay that ignores the capacitor value at the CTS pin, check the Section 5 to verify variant specific functionality.

#### 10.3.5.1 Sense Time Delay Configuration

SENSE time delay ( $t_{CTS}$ ) occurs when the RESET is transitioning from a non-fault state ( $V_{OH}$ ) to a fault state ( $V_{OL}$ ). The time delay ( $t_{CTS}$ ) can be programmed by connecting a capacitor between CTS pin and GND.

The relationship between external capacitor  $C_{CTS EXT (typ)}$  and the time delay  $t_{CTS (typ)}$  is given by Equation 4.

 $t_{\text{CTS (typ)}} = R_{\text{CTS (typ)}} \times C_{\text{CTS}\_\text{EXT (typ)}} + t_{\text{CTS (no cap)}} \times 10^{-6}$ 

(4)

(6)

 $R_{CTS (typ)}$  = is in mega ohms (M $\Omega$ )

 $C_{CTS\_EXT (typ)}$  = is given in microfarads (µF)

 $t_{CTS (typ)}$  = is the sense time delay/delays

The sense delay varies according to three variables: the external capacitor ( $C_{CTS\_EXT}$ ), CTS pin internal resistance ( $R_{CTS}$ ) provided in Section 7.5, and the constant ( $t_{CTS (no cap)}$ ) provided in Section 7.6. The minimum and maximum variance due to the constant is show in Equation 5 and Equation 6:

$$t_{\text{CTS (min)}} = R_{\text{CTS (min)}} \times C_{\text{CTS}\_\text{EXT (min)}} + t_{\text{CTS (no cap (min))}} \times 10^{-6}$$
(5)

$$t_{\text{CTR (max)}} = R_{\text{CTS (max)}} \times C_{\text{CTS EXT (max)}} + t_{\text{CTSx (no cap (max))}} \times 10^{-6}$$

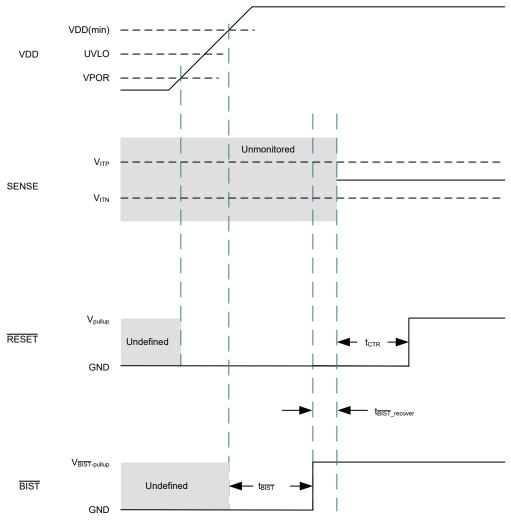
The recommended maximum sense delay capacitor for the TPS3762-Q1 is  $10\mu$ F as this makes sure there is enough time for the capacitor to fully discharge when a voltage fault occurs. Also, having a too large of a capacitor value can cause very slow charge up (rise times) and system noise can cause the internal circuit to trip unpredictably. This leads to a variation in time delay where the delay accuracy can be worse in the presence of system noise.

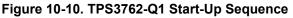
\* Leakages on the capacitor can effect accuracy of sense time delay.



#### 10.3.6 Built-In Self-Test

The TPS3762-Q1 has a Built-In Self-Test (BIST) feature that runs diagnostics internally in the device. During power-up BIST is initiated automatically after crossing  $V_{DD(min)}$ . During BIST the BIST pin and RESET output asserts low and deasserts if the BIST test completes successfully indicating no internal faults in the device. The length of the BIST and BIST assertion is specified by  $t_{BIST}$ . If BIST is not successful, the BIST pin will say asserted low signifying an internal fault. The RESET output will stay assert on BIST failure. During BIST, the device is not monitoring the SENSE pin for faults and the RESET is not dependent on the SENSE pin voltage. The BIST sequence of internal tests verifies the internal signal chain of the device by checking for faults on the internal comparators on the SENSE pin, bandgap voltage, and the RESET output. See Figure 10-10 for more details.

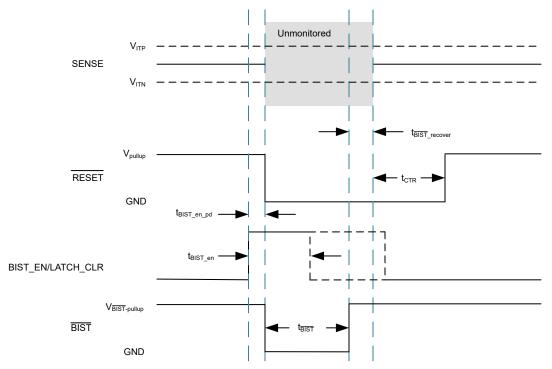




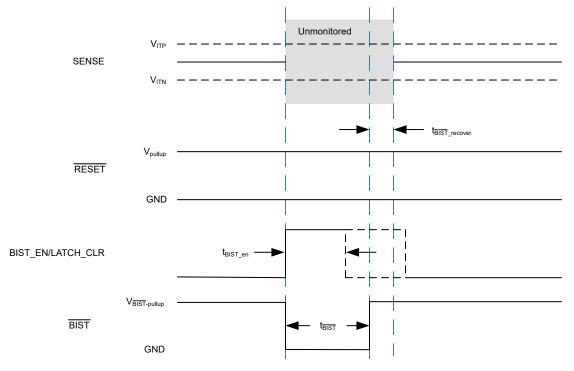
After a successful power-up sequence, BIST can be initiated any time with a logic high input ( $V_{BIST\_EN}$  or  $V_{BIST\_EN/LATCH\_CLR} > 1.3V$ ) on the BIST\_EN / LATCH\\_CLR pin. BIST initiates and the BIST pin asserts only if the SENSE pin is not in a overvoltage or undervoltage fault mode. During this BIST test time period,  $t_{BIST}$ , BIST pin asserts low to signify that BIST has started and RESET assertion is dependent on the device variant. Upon a successful BIST the BIST pin and RESET pin are deasserted. If BIST is not successful due to an internal device not working properly, the RESET pin and BIST pin remain asserted low signifying a fault internal to the device. See Figure 10-11 and Figure 10-12 for more details.

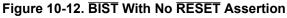
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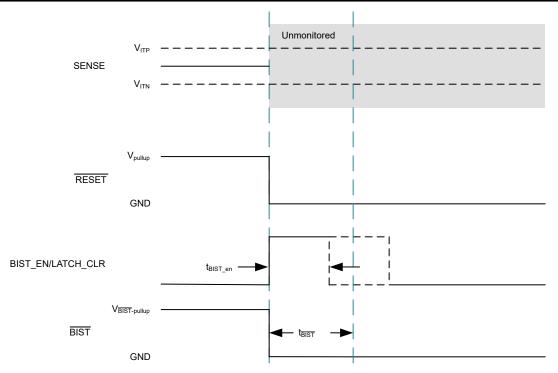


## Figure 10-11. BIST With RESET Assertion

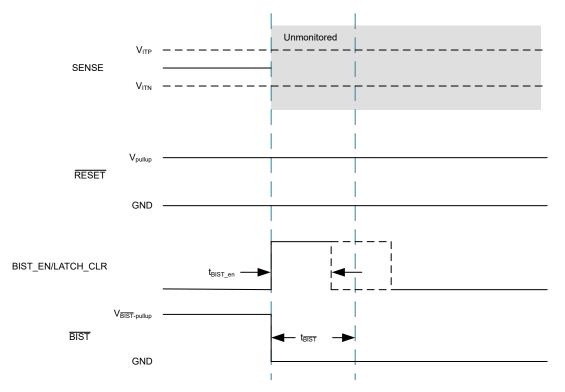








## Figure 10-13. BIST Fail With RESET Assertion







## **10.4 Device Functional Modes**

Table 10-2. Undervoltage Detect Functional Mode Truth Table

	S	ENSE			OUTPUT <sup>(2)</sup> (RESET PIN)	
DESCRIPTION	PREVIOUS CONDITION	CURRENT CONDITION	CTR <sup>(1)</sup> / MR PIN	V <sub>DD</sub> PIN		
Normal Operation	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High	
Undervoltage Detection	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low	
Undervoltage Detection	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low	
Normal Operation	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub> + HYS	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High	
UVLO Engaged	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{POR} < V_{DD} < V_{DD(MIN)}$	Low	
Below V <sub>POR</sub> , Undefined Output	SENSE > V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	V <sub>DD</sub> < V <sub>POR</sub>	Undefined	

Reset time delay is ignored in the truth table. (1)

(2) Open-drain active low output requires an external pull-up resistor to a pull-up voltage.

	S	ENSE				
DESCRIPTION	PREVIOUS CONDITION	CURRENT CONDITION	CTR <sup>(1)</sup> / MR PIN	V <sub>DD</sub> PIN	OUTPUT <sup>(2)</sup> (RESET PIN)	
Normal Operation	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High	
Overvoltage Detection	SENSE < V <sub>ITN</sub>	SENSE > V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low	
Overvoltage Detection	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	Low	
Normal Operation	SENSE > V <sub>ITN</sub>	SENSE < V <sub>ITN</sub> - HYS	Open or capacitor connected	$V_{DD} > V_{DD(MIN)}$	High	
UVLO Engaged	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	V <sub>POR</sub> < V <sub>DD</sub> < UVLO	Low	
Below V <sub>POR</sub> , Undefined Output	SENSE < V <sub>ITN</sub>	SENSE < V <sub>ITN</sub>	Open or capacitor connected	V <sub>DD</sub> < V <sub>POR</sub>	Undefined	

T-1-1- 40 0 0 ... . -Mada Truth Tabl -...

(1) Reset time delay is ignored in the truth table.

Open-drain active low output requires an external pull-up resistor to a pull-up voltage. (2)



## **11 Application and Implementation**

#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### **11.1 Application Information**

The following sections describe in detail proper device implementation, depending on the final application requirements.

#### 11.2 Adjustable Voltage Thresholds

Figure 11-1 illustrates an example of how to adjust the voltage threshold with external resistor dividers. The resistors can be calculated depending on the desired voltage threshold and device part number. TI recommends using the adjustable (0.8V voltage threshold device) when setting adjustable voltage thresholds. This variant bypasses the internal resistor ladder.

For example, consider a 12V rail, V<sub>MON</sub>, being monitored for overvoltage (OV) using of the TPS3762D02OVDDFRQ1 variant, as shown in Figure 11-1. The monitored OV threshold, denoted as V<sub>MON+</sub>, is the desired voltage where the device asserts the reset. For this example V<sub>MON+</sub> = 35V. To assert an overvoltage reset the voltage at the sense pin, V<sub>SENSE</sub>, needs to be equal to the input threshold positive, V<sub>ITP</sub>. For this example variant V<sub>SENSE</sub> = V<sub>ITP</sub> = 0.8V. Using R<sub>1</sub> and R<sub>2</sub> the correlation between V<sub>MON+</sub> and V<sub>SENSE</sub> can be seen in Equation 8. Assuming R<sub>2</sub> = 10k $\Omega$ , and R<sub>1</sub> can be calculated as R<sub>1</sub> = 427.5k $\Omega$ .

$$V_{SENSE} = V_{MON+} \times (R_2 \div (R_1 + R_2))$$

The TPS3762D02OVDDFRQ1 comes with variant specific 2%, 5%, or 10% voltage threshold hysteresis. For the reset signal to become deasserted,  $V_{MON}$  must go below  $V_{ITP}$  -  $V_{HYS}$ . For this example variant a 2% voltage threshold hysteresis was selected. Therefore,  $V_{MON}$  equals 34.3V when the reset signal becomes deasserted.

There are inaccuracies that must be taken into consideration while adjusting voltage thresholds. Aside from the tolerance of the resistor divider, there is the internal resistance of the SENSE pin that can affect the accuracy of the resistor divider. Although expected to be very high impedance, users are recommended to calculate the values for the design specifications. The internal SENSE resistance ( $R_{SENSE}$ ) can be calculated by the SENSE voltage ( $V_{SENSE}$ ) divided by the SENSE current ( $I_{SENSE}$ ) as shown in Equation 9.  $V_{SENSE}$  can be calculated using Equation 7 depending on the resistor divider and monitored voltage.  $I_{SENSE}$  can be calculated using Equation 8.

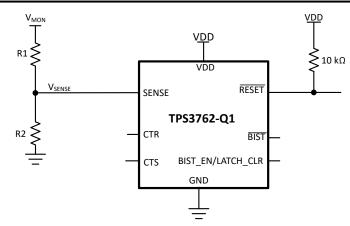
$$I_{\text{SENSE}} = [(V_{\text{MON}} - V_{\text{SENSE}}) \div R_1] - (V_{\text{SENSE}} \div R_2)$$
(8)

 $R_{SENSE} = V_{SENSE} \div I_{SENSE}$ 

(9)

(7)







## 11.3 Typical Application

## 11.3.1 Design 1: Off-Battery Monitoring

This application is intended for the initial power stage in applications with the 12V batteries. The TPS3762-Q1 utilizes high-voltage SENSE and  $V_{DD}$  inputs to monitor an automotive battery.

Figure 11-6 illustrates an example of how the TPS3762-Q1 is monitoring the battery voltage while being powered by it, as well.

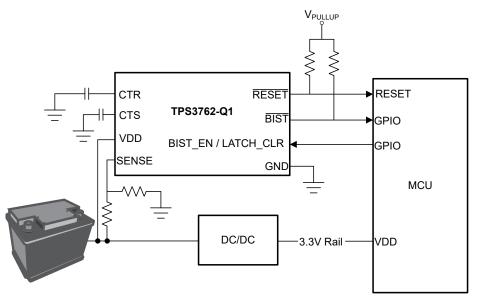


Figure 11-2. Off-Battery Monitoring



#### 11.3.1.1 Design Requirements

PARAMETER	DESIGN REQUIREMENT
Voltage Threshold	Typical OV voltage threshold 30V.
Maximum Input Power	Operate with power supply input up to 65V
Output Logic	Open-Drain
SENSE Delay	>100ms
RESET Delay	>300ms
Output Features	Output latching and built-in self-test

#### Table 11-1. Design Parameters

#### 11.3.1.2 Detailed Design Procedure

The TPS3762-Q1 utilizes high-voltage SENSE and  $V_{DD}$  inputs to monitor an automotive battery. In this design example TPS3762D02OVDDFRQ1 is used.

#### 11.3.1.2.1 Setting Voltage Threshold

The positive-going threshold voltage,  $V_{ITP}$ , is set by the device variant. In this example, the nominal supply voltage from the battery is 12V. Setting a overvoltage threshold of 30V makes sure that the device resets before supply voltage violates the allowed boundary. The adjustable voltage variant is chosen and  $R_1$  and  $R_2$  are adjusted to meet the threshold. Assuming  $R_2$  equal to 10k $\Omega$  and  $R_1$  is calculated as 365k $\Omega$ . For additional information on selecting resistor values see Section 11.2. TPS3762-Q1 also supports fixed voltage threshold variants. Threshold voltage decoding can be found in Device Decoder.

#### 11.3.1.2.2 Meeting the Sense and Reset Delay

The TPS3762-Q1 features both reset assertion (sense) delay,  $t_{CTS}$ , and reset deassertion (reset) delay,  $t_{CTR}$ . The TPS3762-Q1 features two options for selecting sense and reset delays: fixed delays and capacitor-programmable delays. For the device variant used in this design, TPS3762D02OVDDFRQ1, the capacitor programmable delay is chosen. Section 10.3.5 and Section 10.3.4 show how to set the timings for the capacitor-programmable delays. The application requires greater than 100 ms sense delay, thus a 0.033  $\mu$ F capacitor is used. The application requires greater than 300 ms reset delay, thus a 0.1  $\mu$ F capacitor is used.

#### 11.3.1.2.3 Setting Supply Voltage

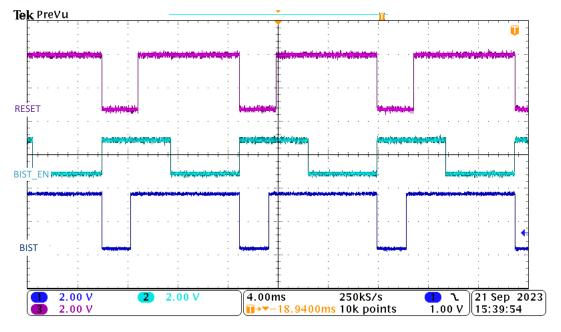
Setting the supply voltage is done by connecting the V<sub>DD</sub> input directly to the battery rail without the need for external circuitry. The device being able to handle 65V on V<sub>DD</sub> means the monitored voltage rail can handle any voltage transience up to 65V. Good analog design practice recommends using a 0.1  $\mu$ F capacitor on the V<sub>DD</sub> pin.

#### 11.3.1.2.4 Initiating Built-In Self-Test and Clearing Latch

Built-In Self-Test (BIST) is asserted on device power-up, as outlined in Figure 10-10. BIST can also be initiated any time by a rising edge that crosses the voltage logic high input ( $V_{BIST\_EN}$  or  $V_{BIST\_EN/LATCH\_CLR} > 1.3V$ ) on the BIST\_EN / LATCH\_CLR pin, as outlined in Figure 10-11. Output reset latching is set by the device variant. For the device variant used in this design, TPS3762D02OVDDFRQ1, the output has latch. Device specific output reset latching feature can be found in Device Decoder. To clear the latch a logic high input on the BIST\_EN / LATCH\_CLR pin is required. When clearing latch, BIST is initiated and the RESET returns logic level high once tBIST + tBIST\_recover + tCTR has expired, outlined in Figure 10-6. While V<sub>BIST\\_EN/LATCH\_CLR</sub> > 1.3V, the device is in latch disabled mode and the RESET does not latch for OV and UV on SENSE pin. While the device is in latch disabled mode the RESET still asserts for OV and UV faults.



#### 11.3.1.3 Application Curves





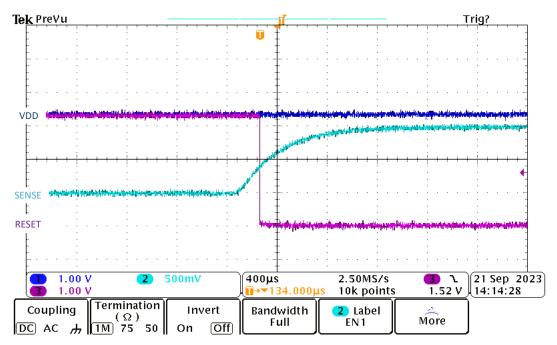


Figure 11-4. Overvoltage RESET Latching Waveform

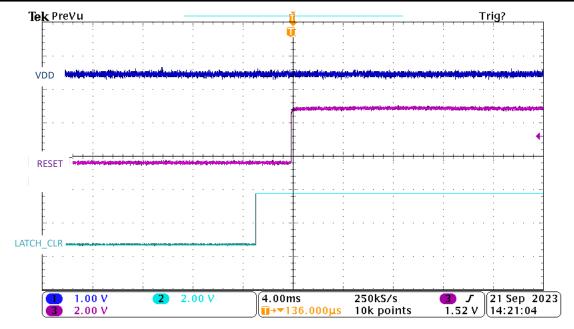


Figure 11-5. Overvoltage RESET Unlatching Waveform



(13)

(14)

#### **11.4 Power Supply Recommendations**

TPS3762-Q1 is designed to operate from an input supply with a V<sub>DD</sub> voltage between 2.7V (minimum operation) to 65V (maximum operation). Good analog design practice recommends placing a minimum  $0.1\mu$ F ceramic capacitor as near as possible to the V<sub>DD</sub> pin.

#### 11.4.1 Power Dissipation and Device Operation

The permissible power dissipation for any package is a measure of the capability of the device to pass heat from the power source, the junctions of the IC, to the ultimate heat sink, the ambient environment. Thus, the power dissipation is dependent on the ambient temperature and the thermal resistance across the various interfaces between the die junction and ambient air.

The maximum continuous allowable power dissipation for the device in a given package can be calculated using Equation 10:

$$P_{D-MAX} = \left( \left( T_{J-MAX} - T_A \right) / R_{\theta JA} \right)$$
(10)

The actual power being dissipated in the device can be represented by Equation 11:

$P_D = V_{DD} \times I_{DD} + p_{RESET}$	(11)

p<sub>RESET</sub> is calculated by Equation 12 or Equation 13

$$p_{\text{RESET}(\text{PUSHPULL})} = V_{\text{DD}} - V_{\text{RESET}} \times I_{\text{RESET}}$$
(12)

 $p_{\text{RESET (OPEN-DRAIN)}} = V_{\text{RESET }} \times I_{\text{RESET}}$ 

Equation 10 and Equation 11 establish the relationship between the maximum power dissipation allowed due to thermal consideration, the voltage drop across the device, and the continuous current capability of the device. These two equations must be used to determine the optimum operating conditions for the device in the application.

In applications where lower power dissipation (P<sub>D</sub>) and/or excellent package thermal resistance (R<sub> $\theta$ JA</sub>) is present, the maximum ambient temperature (T<sub>A-MAX</sub>) can be increased.

In applications where high power dissipation and/or poor package thermal resistance is present, the maximum ambient temperature ( $T_{A-MAX}$ ) may have to be de-rated.  $T_{A-MAX}$  is dependent on the maximum operating junction temperature ( $T_{J-MAX-OP} = 125^{\circ}$ C), the maximum allowable power dissipation in the device package in the application ( $P_{D-MAX}$ ), and the junction-to ambient thermal resistance of the part/package in the application ( $R_{\theta JA}$ ), as given by Equation 14:

$$T_{A-MAX} = (T_{J-MAX-OP} - (R_{\theta JA} \times P_{D-MAX}))$$

#### 11.5 Layout

#### 11.5.1 Layout Guidelines

- Make sure that the connection to the VDD pin is low impedance. Good analog design practice is to place a
  greater than 0.1µF ceramic capacitor as near as possible to the VDD pin.
- To further improve the noise immunity on the SENSE pins, placing a 10nF to 100nF capacitor between the SENSE pin and GND can reduce the sensitivity to transient voltages on the monitored signal.
- If a capacitor is used on CTS or CTR, place these components as close as possible to the respective pins. If the capacitor adjustable pins are left unconnected, make sure to minimize the amount of parasitic capacitance on the pins to less than 5pF.
- Place the pull-up resistors on RESET as close to the pin as possible.
- When laying out metal traces, separate high voltage traces from low voltage traces as much as possible. If high and low voltage traces need to run close by, spacing between traces must be greater than 20mils (0.5mm).



• Do not have high voltage metal pads or traces closer than 20 mils (0.5mm) to the low voltage metal pads or traces.

#### 11.5.2 Layout Example

The layout example in Figure 11-6 shows how the TPS3762-Q1 is laid out on a printed circuit board (PCB) with user-defined delays.

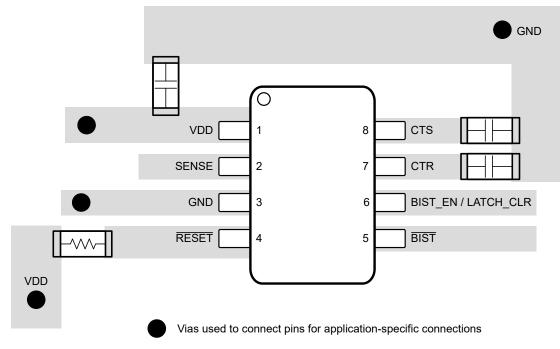


Figure 11-6. TPS3762-Q1 Recommended Layout



## **12 Device and Documentation Support**

### **12.1 Receiving Notification of Documentation Updates**

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### **12.2 Support Resources**

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 12.3 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

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#### **12.4 Electrostatic Discharge Caution**



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 12.5 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

#### **13 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision * (October 2023) to Revision A (May 2024)	Page

٠	Production Data release	1

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TPS3762D02OVDDFRQ1	ACTIVE	SOT-23-THIN	DDF	8	3000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	62D02	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF TPS3762-Q1 :



www.ti.com

17-Dec-2024

Catalog : TPS3762

NOTE: Qualified Version Definitions:

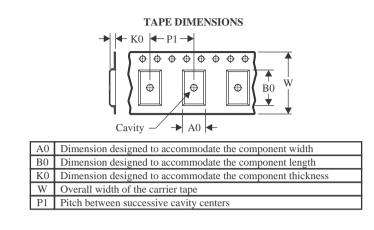
Catalog - TI's standard catalog product



www.ti.com

## TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions a	are nominal
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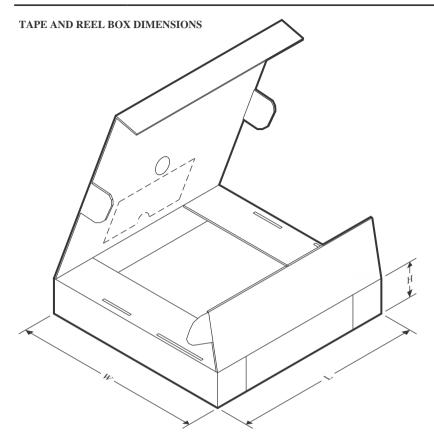
Device		Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3762D02OVDDFRQ1	SOT-23- THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3



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# PACKAGE MATERIALS INFORMATION

14-Dec-2024



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3762D02OVDDFRQ1	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0

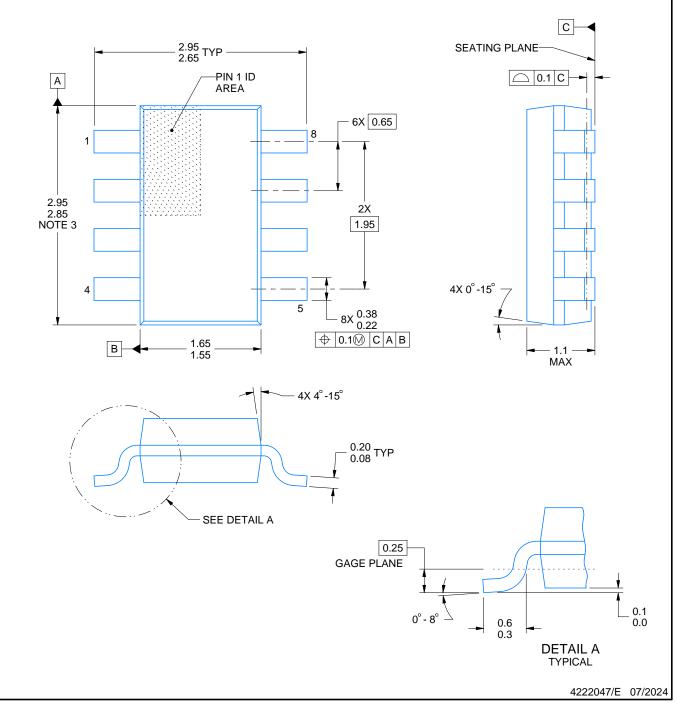
# **DDF0008A**



# **PACKAGE OUTLINE**

## SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.

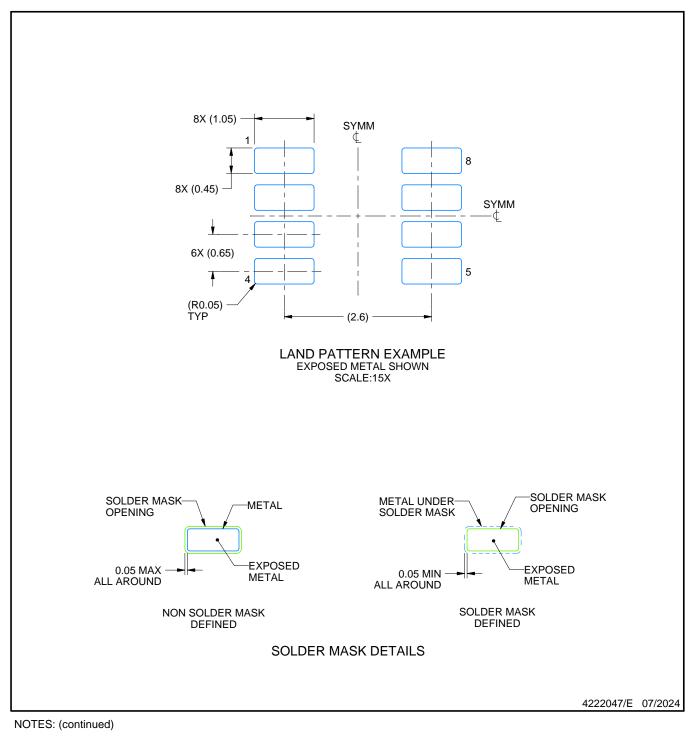


# **DDF0008A**

# **EXAMPLE BOARD LAYOUT**

# SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

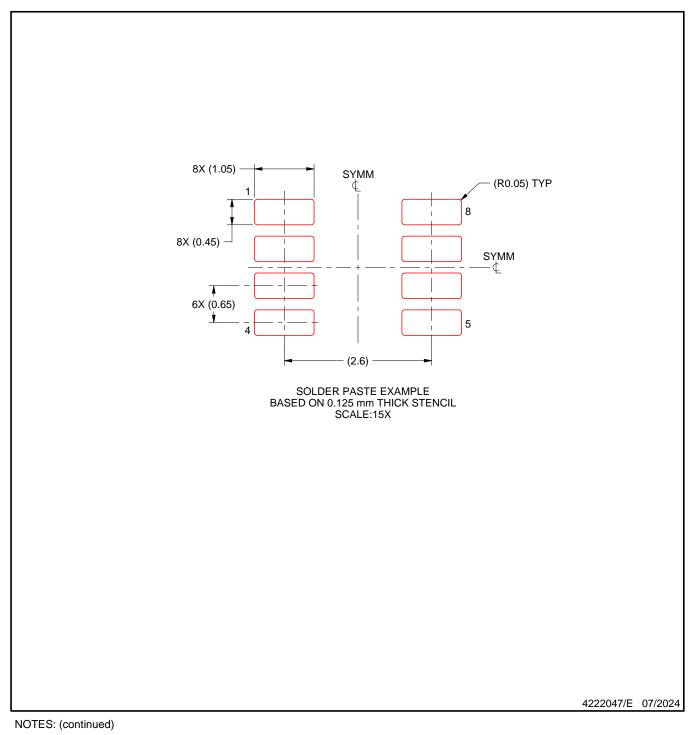


# **DDF0008A**

# **EXAMPLE STENCIL DESIGN**

# SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



<sup>6.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



<sup>7.</sup> Board assembly site may have different recommendations for stencil design.

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